Title: Thermally Conductive Coating Composition Honeywell Docket No.: H0003298 (4962) Riordan Docket No.: 52-020-001

Inventor: Zhou et al.

CLAIMS

We claim:

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- A thermal interface composition, comprising:
 at least two siloxane-based compounds,
 at least one inorganic micro-filler material, and
 at least one thermally conductive filler material.
 - 2. The thermal interface composition of claim 1, wherein at least one of the siloxane-based compounds comprises a polysiloxane compound.
- The thermal interface composition of claim 1, wherein at least one of the siloxanebased compounds comprises a hydride-functional siloxane compound.
 - 4. The thermal interface composition of claim 2, wherein the polysiloxane compound comprises a substituted polysiloxane compound.
 - 5. The thermal interface composition of claim 4, wherein the polysiloxane compound is substituted by a functional group comprising an alkyl group, an aromatic group, a halide group or a combination thereof.
 - 6. The thermal interface composition of claim 4, wherein the substituted polysiloxane compound comprises an alkenyl-terminated polyalkylsiloxane.
 - 7. The thermal interface composition of claim 6, wherein the alkenyl-terminated polyalkylsiloxane comprises a vinyl group.
 - 20 8. The thermal interface composition of claim 7, wherein the alkenyl-terminated polyalkylsiloxane further comprises a methyl group.
 - 9. The thermal interface composition of claim 5, wherein the polysiloxane compound comprises vinylmethylcyclotetrasiloxane, polytetradecylmethylsiloxane, polyoctylmethylsiloxane, decylmethylsiloxane, butylated aryloxy-

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propylmethylsiloxane, octadecylmethylsiloxane, dimethylsiloxane or a combination thereof.

- 10. The thermal interface composition of claim 3, wherein the hydride-functional siloxane comprises methylhydrosiloxane.
- 5 11. The thermal interface composition of claim 1, wherein the inorganic micro-filler material comprises silicon dioxide.
 - 12. The thermal interface composition of claim 1, wherein the inorganic micro-filler material comprises a powder.
- 13. The thermal interface composition of claim 1, wherein the inorganic micro-filler material comprises a flake.
 - 14. The thermal interface composition of claim 1, wherein the thermally conductive filler material comprises a transition metal.
 - 15. The thermal interface composition of claim 1, wherein the thermally conductive filler material comprises boron.
- 15 16. The thermal interface composition of claim 14, wherein the transition metal comprises copper.
 - 17. The thermal interface composition of claim 15, wherein the thermally conductive filler material comprises boron nitride.
 - 18. The thermal interface material of claim 1, further comprising at least one additive.
- 20 19. The thermal interface material of claim 18, wherein the additive comprises a catalyst.
 - 20. The thermal interface material of claim 18, wherein the additive comprises an inhibitor.
 - 21. The thermal interface material of claim 18, wherein the additive comprises a rheological modifier.

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- 22. The thermal interface composition of claim 19, wherein the catalyst comprises platinum.
- 23. The thermal interface composition of claim 20, wherein the inhibitor comprises an antioxidant.
- 5 24. The thermal interface composition of claim 21, wherein the rheological modifier comprises at least one solvent.
 - 25. A coating composition comprising the thermal interface composition of claim 1.
 - 26. A coating composition comprising the thermal interface composition of claim 18.
 - 27. An electronic component comprising the thermal interface composition of claim 1.
- 10 28. An electronic component comprising the thermal interface composition of claim 18.
 - 29. An electronic component comprising the coating solution of claim 25.
 - 30. An electronic component comprising the coating solution of claim 26.
 - 31. A semiconductor component comprising the thermal interface composition of claim

1.

15 32. A semiconductor component comprising the thermal interface composition of claim

18.

- 33. A semiconductor component comprising the coating solution of claim 25.
- 34. A semiconductor component comprising the coating solution of claim 26.
- 35. A method of forming a thermal interface material, comprising:
- 20 providing at least two siloxane-based compounds,

providing at least one inorganic micro-filler material,

providing at least one thermally conductive filler material, and

combining the at least two siloxane-based compounds, the at least one inorganic micro-filler material and the at least one thermally conductive filler material.

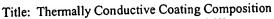
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- The method of claim 35, wherein at least one of the siloxane-based compounds 36. comprises a polysiloxane compound.
- The method of claim 35, wherein at least one of the siloxane-based compounds 37. comprises a hydride-functional siloxane compound.
- The method of claim 36, wherein the polysiloxane compound comprises a 38. 5 substituted polysiloxane compound.
 - The method of claim 38, wherein the polysiloxane compound is substituted by a 39. functional group comprising an alkyl group, an aromatic group, a halide group or a combination thereof.
- The method of claim 38, wherein the substituted polysiloxane compound comprises 40. 10 an alkenyl-terminated polyalkylsiloxane.
 - The method of claim 40, wherein the alkenyl-terminated polyalkylsiloxane 41. comprises a vinyl group.
- The method of claim 41, wherein the alkenyl-terminated polyalkylsiloxane further 42. comprises a methyl group. 15
 - The method of claim 39, wherein the polysiloxane compound comprises 43. polytetradecylmethylsiloxane, vinylmethylcyclotetrasiloxane, aryloxydecylmethylsiloxane, butylated polyoctylmethylsiloxane, propylmethylsiloxane, octadecylmethylsiloxane, dimethylsiloxane or a combination thereof.
- 20
 - The method of claim 37, wherein the hydride-functional siloxane comprises 44. methylhydrosiloxane.
 - The method of claim 35, wherein the inorganic micro-filler material comprises 45. silicon dioxide.
- The method of claim 35, wherein the inorganic micro-filler material comprises a 25 46. powder.



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- 47. The method of claim 35, wherein the inorganic micro-filler material comprises a flake.
- 48. The method of claim 35, wherein the thermally conductive filler material comprises a transition metal.
- 5 49. The method of claim 35, wherein the thermally conductive filler material comprises boron.
 - 50. The method of claim 48, wherein the transition metal comprises copper.
 - 51. The method of claim 49, wherein the thermally conductive filler material comprises boron nitride.
- 10 52. The method of claim 35, further comprising at least one additive.
 - 53. The method of claim 52, wherein the additive comprises a catalyst.
 - 54. The method of claim 52, wherein the additive comprises an inhibitor.
 - 55. The method of claim 52, wherein the additive comprises a rheological modifier.
 - 56. The method of claim 53, wherein the catalyst comprises platinum.
- 15 57. The method of claim 54, wherein the inhibitor comprises an antioxidant.
 - 58. The method of claim 55, wherein the rheological modifier comprises at least one solvent.
 - 59. A coating composition produced from the method of claim 35.
 - 60. A coating composition produced from the method of claim 52.
- 20 61. An electronic component comprising the coating solution of claim 59.
 - 62. An electronic component comprising the coating solution of claim 60.
 - 63. A semiconductor component comprising the coating solution of claim 59.
 - 64. A semiconductor component comprising the coating solution of claim 60.